

Isc P-Channel MOSFET Transistor
TJ15P04M3
• FEATURES

- Low drain-source on-resistance:
 $R_{DS(ON)} = 36m\Omega$ (MAX)
- Enhancement mode:
 $V_{th} = 0.8$ to $2V$ ($V_{DS} = -10V$, $I_D = -7.5A$)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

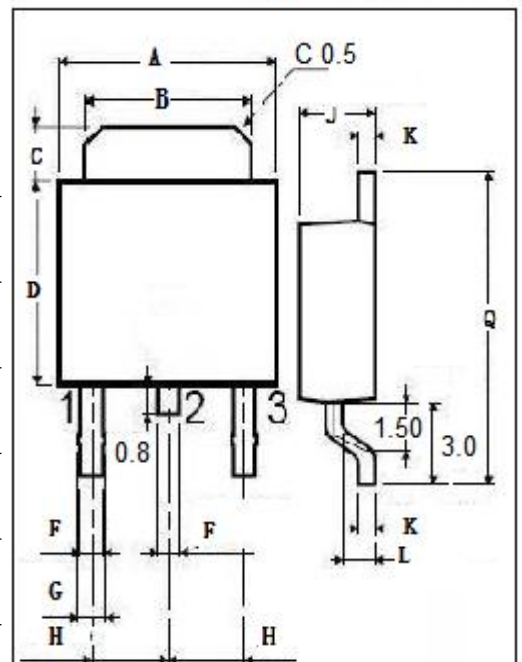
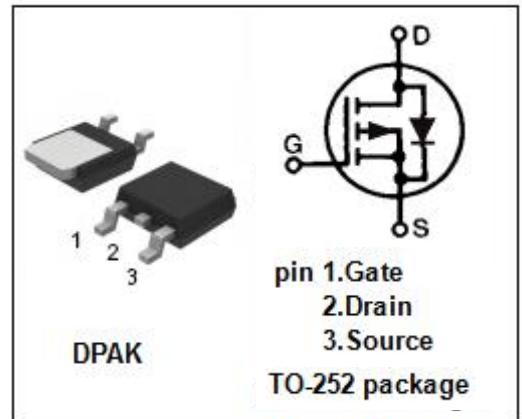
- Switching Voltage Regulators

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DS}	Drain-Source Voltage	-40	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	-15	A
I_{DM}	Drain Current-Single Pulsed	-45	A
P_D	Total Dissipation @ $T_c=25^\circ C$	29	W
T_j	Max. Operating Junction Temperature	150	$^\circ C$
T_{stg}	Storage Temperature	-55~150	$^\circ C$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	4.3	$^\circ C/W$



DIM	mm	
	MIN	MAX
A	6.40	6.60
B	5.20	5.40
C	1.15	1.35
D	5.70	6.10
F	0.65	
G	0.75	
H	2.10	2.50
J	2.10	2.40
K	0.40	0.60
L	0.90	1.10
Q	9.90	10.1

Isc P-Channel MOSFET Transistor**TJ15P04M3****ELECTRICAL CHARACTERISTICS**T_c=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = -10mA	-40			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = -10V; I _D =-0.1mA	-0.8		-2.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = -10V; I _D = -7.5A			36	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = -40V; V _{GS} = 0V			-10	μA
V _{SDF}	Diode forward voltage	I _{DR} =-15A, V _{GS} = 0 V			-1.2	V

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